## NSN 5961-00-457-1171

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### Inclosure Material:

Metal

#### **Overall Length:**

Between 0.115 inches and 0.150 inches

#### Terminal Length:

0.500 inches

#### **Overall Diameter:**

Between 0.209 inches and 0.230 inches

#### **Function For Which Designed:**

Switching

#### Internal Configuration:

Junction contact

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-52

Electrode Internally-electrically Connected To Case:

#### Collector

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

40.0 collector to emitter voltage, dc with base short-circuited to emitter and 15.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

100.00 milliamperes source cutoff current

#### **Power Rating Per Characteristic:**

360.0 milliwatts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

3 uninsulated wire lead

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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